## REFERENCE FREQUENCY 16.368 MHz ，2ND IF FREQUENCY 4．092 MHz RF／IF FREQUENCY DOWN－CONVERTER＋ PLL FREQUENCY SYNTHESIZER IC FOR GPS RECEIVER

## DESCRIPTION

The $\mu$ PB1005GS is a silicon monolithic integrated circuit for GPS receiver．This IC is designed as double conversion RF block integrated RF／IF down－converter＋PLL frequency synthesizer on 1 chip．

The $\mu$ PB1005GS features shrink package，fixed prescaler and supply voltage．The 30－pin plastic SSOP package is suitable for high density surface mounting．The fixed division internal prescaler is needless to input serial counter data．Supply voltage is 3 V ．Thus，the $\mu$ PB1005GS can make RF block fewer components and lower power consumption．

This IC is manufactured using NEC＇s 20 GHz ft NESAT $^{T M}$ III silicon bipolar process．This process uses direct silicon nitride passivation film and gold electrodes．These materials can protect the chip surface from pollution and prevent corrosion／migration．Thus，this IC realizes excellent performance，uniformity and reliability．

## FEATURES

－Double conversion ：fREFin $=16.368 \mathrm{MHz}$ ，f2ndlFout $=4.092 \mathrm{MHz}$
－Integrated RF block ：RF／IF frequency down－converter＋PLL frequency synthesizer
－High－density surface mountable ：30－pin plastic SSOP $(9.85 \times 6.1 \times 2.0 \mathrm{~mm})$
－Needless to input counter data ：fixed division internal prescaler
－VCO side division $\quad: \div 200(\div 25, \div 8$ serial prescaler $)$
－Reference division $: \div 2$
－Supply voltage ：Vcc＝2．7 to 3.3 V
－Low current consumption ：Icc＝ 45.0 mA TYP．＠Vcc $=3.0 \mathrm{~V}$
－Gain adjustable externally ：Gain control voltage pin（control voltage up vs．gain down）

## APPLICATION

－Consumer use GPS receiver of reference frequency 16.368 MHz ，2nd IF frequency 4.092 MHz

## ORDERING INFORMATION

| Part Number | Package | Supplying Form |
| :--- | :--- | :--- |
| $\mu$ PB1005GS－E1 | 30－pin plastic SSOP <br> $(7.62 \mathrm{~mm} \mathrm{(300))}$ | Embossed tape 16 mm wide． <br> Pin 1 is in tape pull－out direction． <br> QTY 2．5 kpcs／reel． |

Remark To order evaluation samples，please contact your local NEC sales office．（Part number for sample order：$\mu$ PB1005GS）

## Caution Electro－static sensitive devices

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## PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



PRODUCT LINE-UP $\left(\mathrm{TA}_{\mathrm{A}}=+\mathbf{2 5}^{\circ} \mathrm{C}, \mathrm{Vcc}=3.0 \mathrm{~V}\right)$

| Type | Part Number | Functions (Frequency unit: MHz) | Vcc <br> (V) | $\begin{gathered} \text { Icc } \\ (\mathrm{mA}) \end{gathered}$ | $\begin{gathered} C G \\ (\mathrm{~dB}) \end{gathered}$ | $\begin{gathered} \mathrm{T}_{\mathrm{A}} \\ \left({ }^{\circ} \mathrm{C}\right) \end{gathered}$ | Package | Status |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| General <br> Purpose <br> Wideband <br> Separate <br> IC | $\mu \mathrm{PC} 2756 \mathrm{~T}$ | RF down-converter with osc. Tr | 2.7 to 3.3 | 6 | 14 | $\begin{aligned} & -40 \text { to } \\ & +85 \end{aligned}$ | 6-pin minimold | Available |
|  | $\mu \mathrm{PC} 2756 \mathrm{~TB}$ |  |  |  |  |  | 6-pin super minimold |  |
|  | $\mu \mathrm{PC} 2753 \mathrm{GR}$ | IF down-converter with gain control amplifier | 2.7 to 3.3 | 6.5 | 60 to 79 |  | 20-pin plastic SSOP |  |
| Clock <br> Frequency <br> Specific <br> 1 chip IC | $\mu \mathrm{PB} 1003 \mathrm{GS}$ | $\begin{array}{\|l} \hline \text { RF/IF down-converter } \\ + \text { PLL synthesizer } \\ \text { REF }=18.414 \\ 1 \mathrm{stIF}=28.644 / 2 \text { ndIF }=1.023 \end{array}$ | 2.7 to 3.3 | 37.5 | 72 to 92 | $\begin{aligned} & -20 \text { to } \\ & +85 \end{aligned}$ | 30-pin plastic SSOP | Discontinued |
|  | $\mu \mathrm{PB} 1004 \mathrm{GS}$ | RF/IF down-converter <br> + PLL synthesizer $\begin{aligned} & \text { REF }=16.368 \\ & 1 \mathrm{stIF}=61.380 / 2 \mathrm{ndIF}=4.092 \end{aligned}$ | 2.7 to 3.3 | 37.5 | 72 to 92 | $\begin{aligned} & -20 \text { to } \\ & +85 \end{aligned}$ |  |  |
|  | $\mu \mathrm{PB} 1005 \mathrm{GS}$ |  | 2.7 to 3.3 | 45.0 | 72 to 92 | $\begin{aligned} & -40 \text { to } \\ & +85 \end{aligned}$ |  | Available |

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail. To know the associated products, please refer to their latest data sheets.

## SYSTEM APPLICATION EXAMPLE

GPS receiver RF block diagram


Caution This diagram schematically shows only the $\mu$ PB1005GS's internal functions on the system. This diagram does not present the actual application circuits.

## ^ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Conditions | Ratings | Unit |
| :--- | :---: | :--- | :---: | :---: |
| Supply Voltage | $\mathrm{V}_{\mathrm{cc}}$ | $\mathrm{T}_{\mathrm{A}=}=+25^{\circ} \mathrm{C}$ | 3.6 | V |
| Total Circuit Current | Icc | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | 128 | mA |
| Power Dissipation | PD | Mounted on double-sided copper clad <br> $50 \times 50 \times 1.6 \mathrm{~mm}$ epoxy glass PWB at $\mathrm{T}_{\mathrm{A}}=+85^{\circ} \mathrm{C}$ | 464 | mW |
| Operating Ambient Temperature | $\mathrm{T}_{\mathrm{A}}$ |  | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | $\mathrm{T}_{\mathrm{Stg}}$ |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

## RECOMMENDED OPERATING RANGE

| Parameter | Symbol | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | Vcc | 2.7 | 3.0 | 3.3 | V |
| Operating Ambient Temperature | TA | -40 | +25 | +85 | ${ }^{\circ} \mathrm{C}$ |
| RF Input Frequency | frFin | - | 1575.42 | - | MHz |
| 1stLO Oscillating Frequency | $\mathrm{f}_{1 \text { stLLoin }}$ | 1616.80 | 1636.80 | 1656.80 | MHz |
| 1stIF Input Frequency | $\mathrm{f}_{1 \text { stIFin }}$ | - | 61.380 | - | MHz |
| 2ndLO Input Frequency | f 2ndLoin | - | 65.472 | - | MHz |
| 2ndIF Input/output Frequency | $\mathrm{f}_{\text {2ndllin }}$ f2ndl\|Fout | - | 4.092 | - | MHz |
| Reference Input/output Frequency | frefin <br> frefout | - | 16.368 | - | MHz |

$\star \quad$ ELECTRICAL CHARACTERISTICS (Unless otherwise specified, $\mathrm{TA}_{\mathrm{A}}=+25^{\circ} \mathrm{C}, \mathrm{Vcc}=3.0 \mathrm{~V}$ )

| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Total Circuit Current | Icctotal | $\mathrm{lcc} 1+\mathrm{lcc} 2+\mathrm{lcc} 3+\mathrm{lcc} 4$ | 32.0 | 45.0 | 60.0 | mA |
| RF Down-converter Block (frfin $=1575.42 \mathrm{MHz}$, $\mathrm{f}_{\text {stLoin }}=1636.80 \mathrm{MHz}$, $\mathrm{P}_{\text {Loin }}=-10 \mathrm{dBm}, \mathrm{Z} \mathrm{L}=\mathrm{Zs}_{\mathrm{s}}=50 \Omega$ ) |  |  |  |  |  |  |
| Circuit Current 1 | Icc1 | No Signals | 6.0 | 10.0 | 14.0 | mA |
| RF Conversion Gain | CGrF | $\mathrm{PrFin}^{\text {a }}=-40 \mathrm{dBm}$ | 12.5 | 15.5 | 18.5 | dB |
| RF-SSB Noise Figure | NFRF | $\mathrm{P}_{\text {RFin }}=-40 \mathrm{dBm}$ | 7 | 10 | 13 | dB |
| Maximum IF Output Power | Po(sat)RF | PrFin $=-10 \mathrm{dBm}$ | -5.5 | -2.5 | +0.5 | dBm |
| IF Down-converter Block (fistlifin $=61.38 \mathrm{MHz}$, $\mathrm{f}_{\text {ndoloin }}=65.472 \mathrm{MHz}, \mathrm{Zs}=50 \Omega, \mathrm{ZL}=2 \mathrm{k} \Omega$ ) |  |  |  |  |  |  |
| Circuit Current 2 | Icc2 | No Signals | 3.4 | 5.3 | 7.2 | mA |
| IF Voltage Conversion Gain | CG(GV)IF | at Maximum Gain, $\mathrm{P}_{1 \text { stIFin }}=-50 \mathrm{dBm}$ | 38 | 41 | 44 | dB |
| IF-SSB Noise Figure | NFiF | at Maximum Gain, $\mathrm{P}_{1 \text { stifin }}=-50 \mathrm{dBm}$ | 8.5 | 11.5 | 14.5 | dB |
| Maximum 2nd IF Output Power | $\mathrm{Po}($ (sat) $) \mathrm{F}$ | at Maximum Gain, $\mathrm{P}_{1 \text { stIFin }}=-20 \mathrm{dBm}$ | -9.5 | -6.5 | -3.5 | dBm |
| Gain Control Voltage | VGc | Voltage at Maximum Gain of CGIF | - | - | 1.0 | V |
| Gain Control Range | Dgc | $\mathrm{P}_{1 \text { stlifin }}=-50 \mathrm{dBm}$ | 20 | - | - | dB |
| 2nd IF Amplifier ( $\mathrm{f}_{\text {nndll }}=4.092 \mathrm{MHz}, \mathrm{Zs}=50 \Omega, \mathrm{ZL}=2 \mathrm{k} \Omega$ ) |  |  |  |  |  |  |
| Circuit Current 3 | Icc3 | No Signals | 1.55 | 2.40 | 3.25 | mA |
| Voltage Gain | Gv | $\mathrm{P}_{\text {2ndilin }}=-60 \mathrm{dBm}$ | 37 | 40 | 43 | dB |
| Maximum Output Power | Po (sat) | $\mathrm{P}_{\text {2ndlifin }}=-30 \mathrm{dBm}$ | -14.5 | -11.5 | -8.5 | dBm |
| PLL Synthesizer Block |  |  |  |  |  |  |
| Circuit Current 4 | Icc4 | PLL All Block Operating | 18.5 | 28.5 | 38.5 | mA |
| Phase Comparing Frequency | fPD | PLL Loop | 8.0 | 8.184 | 8.4 | MHz |
| Reference Input Minimum Level | VREFin | $\mathrm{Z} \mathrm{L}=10 \mathrm{k} \Omega / / 20 \mathrm{pF}$ (Impedance of measurement equipment) | 200 | - | - | mV P.P |
| Loop Filter Output Level (H) | $\mathrm{V}_{\text {LP(H) }}$ |  | 2.8 | - | - | V |
| Loop Filter Output Level (L) | VLP(L) |  | - | - | 0.4 | V |
| Reference Output Swing | $V_{\text {REFout }}$ | $Z \mathrm{~L}=10 \mathrm{k} \Omega / / 2 \mathrm{pF}$ (Impedance of measurement equipment) | 1.0 | - | - | VP.P |

STANDARD CHARACTERISTICS (Unless otherwise specified $\mathrm{T}_{\mathrm{A}}=\boldsymbol{+ 2 5 ^ { \circ }} \mathbf{C}, \mathrm{Vcc}=\mathbf{3 . 0} \mathrm{V}$ )

| Parameter | Symbol | Conditions | Reference | Unit |
| :---: | :---: | :---: | :---: | :---: |
| RF Down-converter Block ( $\mathrm{P}_{1 \text { stLOin }}=-10 \mathrm{dBm}, \mathrm{Z} \mathrm{L}=\mathrm{Zs}=50 \Omega$ ) |  |  |  |  |
| LO Leakage to IF Pin | LOif | $\mathrm{f}_{1 \text { stLOin }}=1636.80 \mathrm{MHz}$ | -30 | dBm |
| LO Leakage to RF Pin | LOrf | $\mathrm{f}_{1 \text { stLOin }}=1636.80 \mathrm{MHz}$ | -30 | dBm |
| Input 3rd Order Intercept Point | IIP3RF | $\begin{aligned} & \mathrm{f}_{\mathrm{RFin}} 1=1600 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFin}} 2=1605 \mathrm{MHz} \\ & \mathrm{f}_{1 \text { stLOin }}=1660 \mathrm{MHz} \end{aligned}$ | -13 | dBm |
| IF Down-converter Block (1stLO oscillating, $\mathrm{Z}_{\mathrm{s}}=50 \Omega$, Z L $=2 \mathrm{k} \Omega$ ) |  |  |  |  |
| LO Leakage to 2nd IF Pin | LO2ndif | $\mathrm{f}_{\text {2ndLOin }}=65.472 \mathrm{MHz}$ | -20 | dBm |
| LO Leakage to 1st IF Pin | LO1stif | $\mathrm{f}_{\text {2ndLOin }}=65.472 \mathrm{MHz}$ | -40 | dBm |
| Input 3rd Order Intercept Point | IIP3IF | $\begin{aligned} & \mathrm{f}_{1 \text { stIFin } 1}=61.38 \mathrm{MHz}, \mathrm{f}_{1 \text { stIFIF2 }}=61.48 \mathrm{MHz} \\ & \mathrm{f}_{\text {2ndLOin }}=65.472 \mathrm{MHz} \end{aligned}$ | -34 | dBm |

## PIN EXPLANATION

| $\begin{aligned} & \text { Pin } \\ & \text { No. } \end{aligned}$ | Pin Name | Applied Voltage (V) | Pin <br> Voltage <br> (V) | Function and Application | Internal Equivalent Circuit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 3 | RX-MIXout | - | 1.68 | Output pin of RF mixer. 1st IF filter must be inserted between pin $1 \& 3$. |  |
| 4 | Vcc (RF-MIX) | 2.7 to 3.3 | - | Supply voltage pin of RF mixer block. This pin must be decoupled with capacitor (eg. 1000 pF ). |  |
| 5 | RF-MIX ${ }_{\text {in }}$ | - | 1.20 | Input pin of RF mixer. <br> 1575.42 MHz band pass filter can be inserted between pin 5 and external LNA. |  |
| 6 | GND (RF-MIX) | 0 | - | Ground pin RF mixer. |  |
| 7 | $\begin{array}{\|l} \mathrm{V} \mathrm{Vc} \\ \text { (1stLO-OSC) } \end{array}$ | 2.7 to 3.3 | - | Supply voltage pin of differential amplifier for 1st LO oscillator circuit. |  |
| 8 | 1stLO-OSC1 | - | 1.88 | Pin 8 \& 9 are each base pin of differential amplifier for 1st LO oscillator. These pins should be equipped with LC and varactor to oscillate on 1636.80 MHz as VCO. |  |
| 9 | 1stLO-OSC2 | - | 1.88 |  |  |
| 10 | $\begin{aligned} & \text { GND } \\ & \text { (1stLO-OSC) } \end{aligned}$ | 0 | - | Ground pin of differential amplifier for 1st LO oscillator circuit. |  |
| 11 | Vcc (phase detector) | 2.7 to 3.3 | - | Supply voltage pin of phase detector and active loop filter. | (11) $\square$ |
| 12 | PD-Vout3 | Pull-up <br> with resistor | - | Pins of active loop filter for tuning voltage output. The active transistors configured with darlington pair are built on chip. Pin 14 should be pulled down with external resistor. Pin 12 to 13 should be equipped with external RC in order to adjust dumping factor and cutoff frequency. This tuning voltage output must be connected to varactor diode of 1st LO-OSC. |  |
| 13 | PD-Vout2 | - | Output in accordance with phase difference |  |  |
| 14 | PD-Vout 1 | Pull-up <br> with resistor | - |  |  |
| 15 | GND (phase detector) | 0 | - | Ground pin of phase detector + active loop filter. |  |


| Pin <br> No. | Pin Name | Applied <br> Voltage <br> (V) | Pin <br> Voltage <br> (V) | Function and Application | Internal Equivalent Circuit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 16 | Vcc <br> (divider block) | 2.7 to 3.3 | - | Supply voltage pin of prescalers. |  |
| 17 | LOout | - | 2.08 | Monitor pin of comparison frequency at phase detector. |  |
| 18 | GND <br> (divider block) | 0 | - | Ground pin of prescalers + LOout amplifier |  |
| 19 | REFin | - | 1.96 | Input pin of reference frequency. <br> This pin should be equipped with external 16.368 MHz oscillator (e.g. TCXO). |  |
| 20 | Vcc <br> (reference <br> block) | 2.7 to 3.3 | - | Supply voltage pin of input/output amplifiers in reference block. |  |
| 21 | REF ${ }_{\text {out }}$ | - | 1.65 | Output pin of reference frequency. The frequency from pin 19 can be took out as 1 Vp-p swing. |  |
| 22 | 2ndlFout | - | 1.56 | Output pin of 2nd IF amplifier. This pin output 4.092 MHz clipped sinewave. <br> This pin should be equipped with external inverter to adjust level to next stage on user's system. |  |
| 23 | Vcc <br> (2ndIF-AMP) | 2.7 to 3.3 | - | Supply voltage pin of 2nd IF amplifier. |  |
| 24 | 2ndlF bypass | - | 2.30 | Bypass pin of 2nd IF amplifier input 1. This pin should be grounded through capacitor. |  |
| 25 | 2ndIFin2 | - | 2.35 | Pin of 2nd IF amplifier input 2. This pin should be grounded through capacitor. |  |
| 26 | 2ndIFin 1 | - | 2.35 | Pin of 2nd IF amplifier input 1. 2nd IF filter can be inserted between pin 26 \& 28. |  |
| 27 | GND <br> (2ndIF-AMP) | 0 | - | Ground pin of 2nd IF amplifier. |  |


| Pin <br> No. | Pin Name | Applied <br> Voltage <br> (V) | Pin <br> Voltage <br> (V) | Function and Application | Internal Equivalent Circuit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 28 | IF-MIX ${ }_{\text {out }}$ | - | 1.15 | Output pin from IF mixer. IF mixer output signal goes through gain control amplifier before this emitter follower output port. | $30$ |
| 29 | VGc (IF-MIX) | 0 to 3.3 | - | Gain control voltage pin of IF mixer output amplifier. This voltage performs forward control (VGc up $\rightarrow$ Gain down). |  |
| 30 | Vcc (IF-MIX) | 2.7 to 3.3 | - | Supply voltage pin of IF mixer, gain control amplifier and emitter follower transistor. | (2) |
| 1 | IF-MIX ${ }_{\text {in }}$ | - | 2.05 | Input pin of IF mixer. |  |
| 2 | GND (IF-MIX) | 0 | - | Ground pin of IF mixer. |  |

Caution Ground pattern on the board must be formed as wide as possible to minimize ground impedance.
$\star$ TYPICAL CHARACTERISTICS (Unless otherwise specified, $\mathrm{T}_{\mathrm{A}}=+\mathbf{2 5}{ }^{\circ} \mathrm{C}, \mathrm{Vcc}=3.0 \mathrm{~V}$ )
-IC TOTAL-

-RF DOWN-CONVERTER BLOCK-





RF CONVERSION GAIN vs. RF INPUT FREQUENCY


3rd ORDER INTERMODULATON DISTORTION, 1st IF OUTPUT POWER OF EACH TONE vs. RF INPUT POWER OF EACH TONE


## -IF DOWN-CONVERTER BLOCK-




IF CONVERSION GAIN vs. 1st IF INPUT FREQUENCY


2nd IF OUTPUT POWER vs. 1st IF INPUT POWER


IF CONVERSION GAIN vs. 1st IF INPUT FREQUENCY




3rd ORDER INTERMODULATION DISTORTION, 2nd IF OUTPUT POWER OF EACH TONE


-IF AMPLIFIER BLOCK-



-PLL SYNTHESIZER BLOCK-




## _REFERENCE BLOCK-



Remark The graphs indicate nominal characteristics.

## TEST CIRCUIT



## Component List

| Form | Symbol | Value |
| :--- | :---: | :---: |
| Chip capacitor | C1 to C5, C8, C11 to C15, C17, C18, C22 | 1000 pF |
|  | $\mathrm{C} 6, \mathrm{C} 7$ | $24 \mathrm{pF}(\mathrm{UJ})$ |
|  | C 9 | 1800 pF |
|  | C 10 | 33 nF |
|  | C 19 | 10000 pF |
|  | C 23 | $1 \mu \mathrm{~F}$ |
| Ceramic capacitor | $\mathrm{C} 16, \mathrm{C} 20$ | $0.1 \mu \mathrm{~F}$ |
|  | C 21 | $0.01 \mu \mathrm{~F}$ |
|  | $\mathrm{R} 1, \mathrm{R} 2$ | $4.7 \mathrm{k} \Omega$ |
|  | R 3 | $6.2 \mathrm{k} \Omega$ |
| Varactor Diode | R 4 | $1.2 \mathrm{k} \Omega$ |
| Chip inductor | $\mathrm{R} 5, \mathrm{R} 6$ | $1.95 \mathrm{k} \Omega$ |

## PACKAGE DIMENSIONS

30 PIN PLASTIC SHRINK SOP (300 mil) (UNIT: mm)


NOTE Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

## NOTE ON CORRECT USE

(1) Observe precautions for handling because of electro-static sensitive devices.
(2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent abnormal oscillation).
(3) Keep the track length of the ground pins as short as possible.
(4) Connect a bypass capacitor (example: 1000 pF ) to the Vcc pin.
(5) Frequency signal input/output pins must be each coupled with capacitor for DC cut.

## RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

| Soldering Method | Soldering Conditions | Recommended Condition Symbol |
| :--- | :--- | :---: |
| Infrared Reflow | Package peak temperature: $235^{\circ} \mathrm{C}$ or below <br> Time: 30 seconds or less (at $210^{\circ} \mathrm{C}$ ) <br> Count: 3, Exposure limit: None ${ }^{\text {Note }}$ | IR35-00-3 |
| VPS | Package peak temperature: $215^{\circ} \mathrm{C}$ or below <br> Time: 40 seconds or less (at $200^{\circ} \mathrm{C}$ ) <br> Count: 3, Exposure limit: None |  |
| Wave Soldering | Soldering bath temperature: $260^{\circ} \mathrm{C}$ or below <br> Time: 10 seconds or less <br> Count: 1, Exposure limit: None ${ }^{\text {Note }}$ | VP15-00-3 |
| Partial Heating | Pin temperature: $300^{\circ} \mathrm{C}$ <br> Time: 3 seconds or less (per side of device) <br> Exposure limit: None ${ }^{\text {Note }}$ | WS60-00-1 |

Note After opening the dry pack, keep it in a place below $25^{\circ} \mathrm{C}$ and $65 \%$ RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).
[MEMO]


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